## Supporting information for

# High-Performance Flexible and Self-Powered Perovskite Photodetector Enabled by Interfacial Strain Engineering Yu Deng,<sup>†</sup> Wenfang Tai,<sup>†</sup> Qi Zhang, Jun Tang, Jinpeng Li, Kai Wang, and Haomiao

Yu\*

Key Laboratory of Luminescence and Optical Information, Ministry of Education, School of Physical Science and Engineering, Beijing Jiaotong University, Beijing 100044, China

### \*Corresponding Author

Haomiao Yu, E-mail: yuhaomiao@bjtu.edu.cn

<sup>†</sup> Y. D. and W. T. contributed equally to this work.

#### **Experimental section**

#### Materials:

The etched PEN/ITO substrates for flexible photodetector were purchased from Advanced Election Technology CO., Ltd. Hole transport material-PEDOT:PSS (Clevios 4083) , electron transport material-PC<sub>61</sub>BM, CH<sub>3</sub>NH<sub>3</sub>PbI<sub>3-x</sub>Cl<sub>x</sub> precursorsmethylammonium iodide (MAI), lead iodide (PbI<sub>2</sub>) and lead chloride (PbCl<sub>2</sub>) were purchased from Xi'an Polymer Light Technology Corp. All the organic solvents include  $\gamma$ -butyrolactone (GBL), Dimethyl sulfoxide (DMSO, 99.9%), 1,2-dichlorobenzene (ODCB, 99.9%), chlorobenzene (CB, 99.9%) were purchased from Sigma Aldrich. Hole transport material-PDCBT was purchased from 1-Material. All reagents and chemicals were used as received without further purification.

#### Perovskite precursor solutions:

 $CH_3NH_3PbI_{3-x}Cl_x$  perovskite precursor solutions were prepared by mixing MAI, PbI<sub>2</sub> and PbCl<sub>2</sub> with a molar ratio of 1.4:1.25:0.15 in a mixed solvent of GBL: DMSO = 7:3 (v:v) with a slight amount of excessive PbI<sub>2</sub> and stirred at 55 °C for 12 hours in a N<sub>2</sub>-filled glove box.

#### Sample preparation and device fabrication:

PEN/ITO substrates were sequentially cleaned by sonication with distilled water, isopropanol, ethanol and then treated with ultraviolet-ozone plasma before spin-coating of the PEDOT:PSS (Clevios 4083). The PEDOT:PSS (Clevios 4083) solution were spin-coated on the PEN/ITO substrates at 4000 rpm for 60 s, and then annealed on a hotplate at 120°C for 15 min. After depositing the PEDOT:PSS layer, an additional hole transport layer PDCBT was spin-coated at 5000 rpm for 50 s. In order to improve the wettability of the perovskite solution on the PDCBT layer, a modified layer was spin coated by a continuous two-step spin-coating method process at 4000 rpm for 20

and 10 s. During the first spin-coating step, 150  $\mu$ L GBL was dripped on top of the PDCBT layer, and during the second spin-coating step, 50  $\mu$ L CB was spin-coated. The perovskite layer was deposited by a continuous two-step spin-coating method process at 1000 rpm and 4000 rpm for 10 and 31 s, respectively. During the second spin-coating step, 400  $\mu$ L CB was dripped on top of the perovskite film. Then, the flexible samples were annealed at 100°C for 10 min and cooled down to room temperature on a glass Petri dish. For the device fabrication, 60  $\mu$ L PC<sub>61</sub>BM solution was deposited at 3000 rpm for 60 s on top of the perovskite film. Finally, it was sequentially deposited PEI (0.05 wt. % in isopropanol) layer at 5000 rpm for 30 s and 70 nm silver electrodes by vacuum thermal evaporation under a vacuum of 5×10<sup>-5</sup> Pa. The working area of the device is 0.038 cm<sup>2</sup>.

#### Device characterization:

Self-built quantum efficiency test system was used to test the responsivity and detectivity. The response speed was studied by an oscilloscope (MSO58, Tektronix) cooperated with a chopper. Surface morphologies of perovskite films were performed using SEM (JSM-6700F, JEOL). UV-vis spectra were conducted by a UV-vis spectrometer (UV-2600, Shimadzu). XRD measurements were obtained using an X-ray diffractometer (Empyrean, PANalytical). Self-built optical path for the linearly/circularly polarized photoexcitation-modulated photocurrent experiments is schematically shown in Figure S3. The excitation light source is 635 nm continuouswave (CW) laser. The angle of quarter wave plate is adjusted to convert linearly polarized light and circularly polarized light, and the photocurrent are monitored by the source meter. Magneto-photocurrent measurements (Electrical transport measurement system, Model EM7, East Changing Technologies) were performed by recording photocurrent as a function of magnetic field. Steady and transient fluorescence spectroscopic measurements were performed using a fluorescence spectrophotometer (Fluorolog-3, Horiba Scientific). Measurement of impedance spectrum was performed using impedance analyzer (E4990A, Keysight). The film thickness was measured by an ellipsometer (RC2-X, J.A. Woollam Co.).



Figure S1. The thicknesses of PDCBT layer, which was measured by an ellipsometer.



Figure S2. Dark current density under zero bias of MAPbI<sub>3-x</sub>Cl<sub>x</sub>-based FSPPD



**Figure S3**. The rise time/decay time for FSPPD with/without PDCBT layer. The rise time of FSPPD was calculated by the time interval for the photocurrent to reach 90% of its highest value, while the decay time was calculated by the time interval for the photocurrent to fall 10% of its highest value.



Figure S4. Normalized responsivity of MAPbI<sub>3-x</sub>Cl<sub>x</sub>-based FSPPD as a function of

bending cycles with bending radius of 5 mm.



**Figure S5**. Grain size distribution histogram of  $MAPbI_{3-x}Cl_x$  film prepared (a) without PDCBT and (b) with PDCBT, obtained by the top view of SEM images.



Figure S6. XRD patterns of  $MAPbI_{3-x}Cl_x$  film prepared with/without PDCBT (a) excluding and (b) including PEN peak.



Figure S7. Experimental setup for the linear/circular photoexcitation-modulated photocurrent measurements.



Figure S8. PL spectra of MAPbI<sub>3-x</sub>Cl<sub>x</sub> films prepared with/without PDCBT.



Figure S9. The band edges of  $MAPbI_{3-x}Cl_x$  film prepared with/without PDCBT determined from Tauc plots.



Figure S10. Energy level diagram of the FSPPD with PDCBT.